

Description

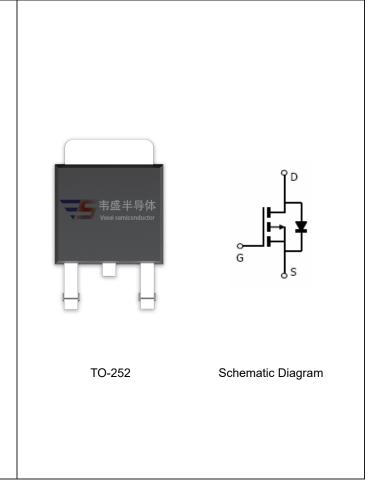
The VSM30P05 uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

General Features

- V_{DS} =-55V, I_{D} =-30A $R_{DS(ON)}$ <40m Ω @ V_{GS} =-10V
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation

Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
VSM30P05-T2	VSM30P05	TO-252	-	-	-

Absolute Maximum Ratings (T_C=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	V _{DS}	-55	V	
Gate-Source Voltage	V _{GS}	±20	V	
Drain Current-Continuous	I _D	-30	Α	
Drain Current-Continuous(T _C =100 °C)	I _D (100°C)	-21	А	
Pulsed Drain Current	I _{DM}	110	А	
Maximum Power Dissipation	P _D	65	W	
Derating factor		0.43	W/°C	
Single pulse avalanche energy (Note 5)	E _{AS}	420	mJ	
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 175	$^{\circ}$	

Thermal Characteristic

Thermal Resistance, Junction-to-Case ^(Note 2)	R _{0JC}	2.3	°C/W



Electrical Characteristics (T_C=25°Cunless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250μA	-55	-	-	V
Zero Gate Voltage Drain Current	o Gate Voltage Drain Current I _{DSS} V		-	-	1	μΑ
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =-250μA	-2	-2.6	-4	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =-10V, I _D =-15A	-	30	40	mΩ
Forward Transconductance	G FS	V _{DS} =-25V,I _D =-16A	8	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C _{lss}	V _{DS} =-30V,V _{GS} =0V,	-	3500	-	PF
Output Capacitance	Coss	V _{DS} =-30V, V _{GS} =0V, F=1.0MHz	-	240	-	PF
Reverse Transfer Capacitance	C _{rss}	r-1.0lvinz	-	153	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t _{d(on)}	V _{DD} =-30V,I _D =-15A	-	12	-	nS
Turn-on Rise Time	t _r		-	15	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =-10 V , R_{GEN} =3 Ω	-	38	-	nS
Turn-Off Fall Time	t _f		-	15	-	nS
Total Gate Charge	Qg	\/ - 20\/ - 454	-	56	-	nC
Gate-Source Charge	Q _{gs}	V_{DS} =-30V, I_{D} =-15A, V_{GS} =-10V	-	11	-	nC
Gate-Drain Charge	Q _{gd}	v _{GS} 10 v	-	24	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =-15A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	-30	Α
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF = -15A	-	-	71	nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	-	170	nC

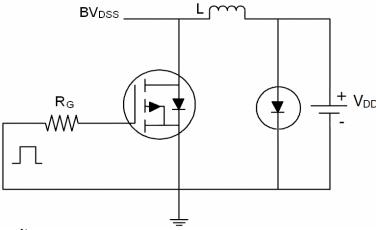
Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board, $t \le 10$ sec.
- **3.** Pulse Test: Pulse Width $\leq 300 \mu s$, Duty Cycle $\leq 2\%$.
- **4.** Guaranteed by design, not subject to production
- **5.** E_{AS} condition: Tj=25 $^{\circ}$ C,V_{DD}=-25V,V_G=-20V,L=0.5mH,Rg=25 Ω ,I_{AS}=29A

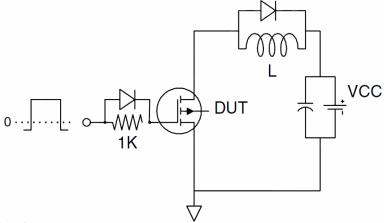


Test Circuit

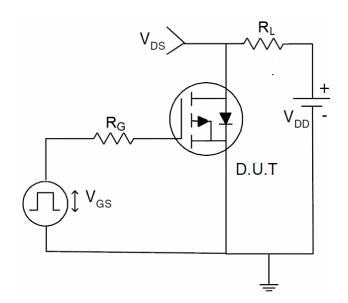
1) E_{AS} Test Circuit



2) Gate Charge Test Circuit



3) Switch Time Test Circuit





Typical Electrical and Thermal Characteristics (Curves)

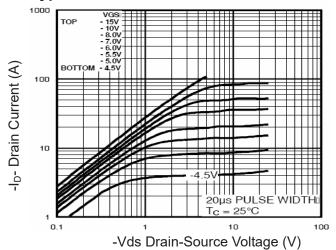


Figure 1 Output Characteristics

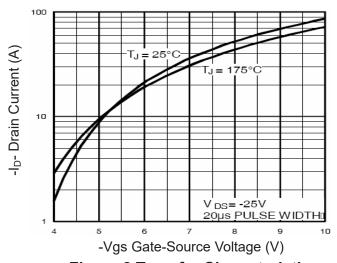


Figure 2 Transfer Characteristics

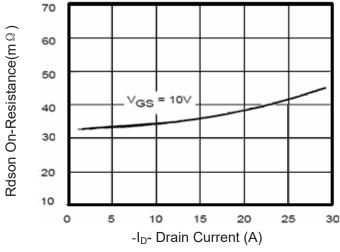


Figure 3 Rdson- Drain Current

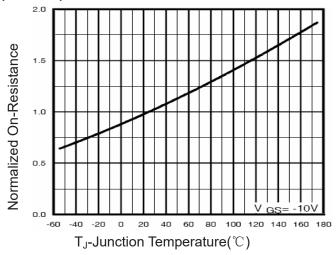


Figure 4 Rdson-JunctionTemperature

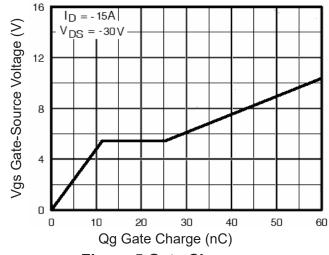


Figure 5 Gate Charge

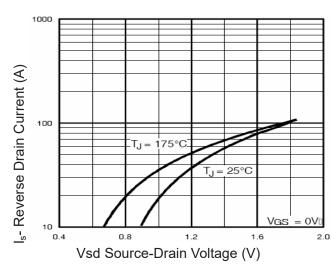


Figure 6 Source- Drain Diode Forward



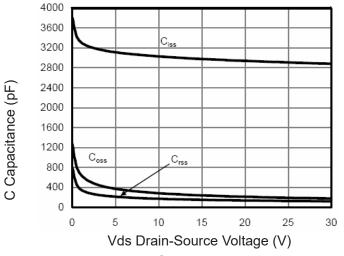


Figure 7 Capacitance vs Vds

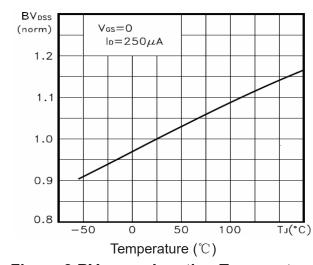


Figure 9 BV_{DSS} vs Junction Temperature

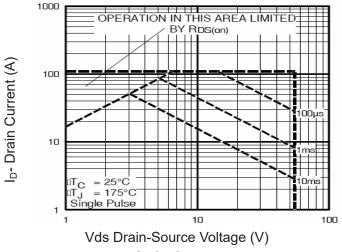


Figure 8 Safe Operation Area

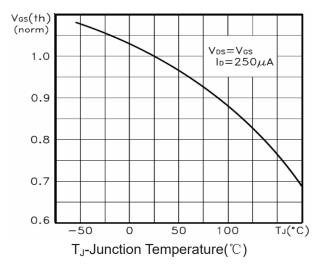
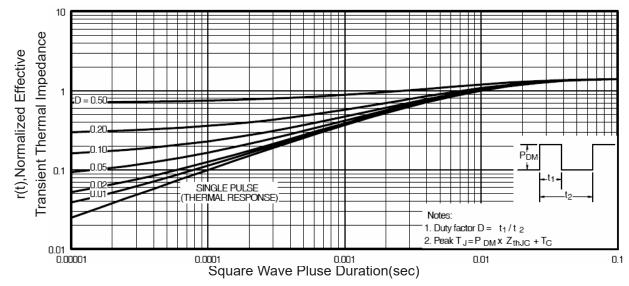


Figure 10 V_{GS(th)} vs Junction Temperature



Normalized BVdss

Figure 11 Normalized Maximum Transient Thermal Impedance